

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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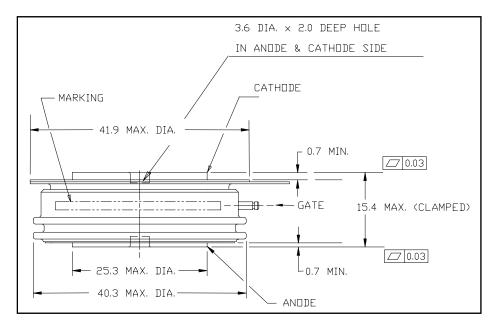


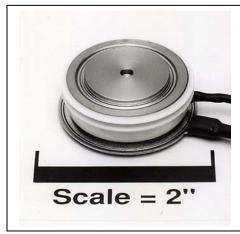






Phase Control SCR 750 Amperes Average 1600 Volts





T7H8 750A Phase Control SCR 750 Amperes Average, 1600 Volts

T7H8 750A (Outline Drawing)

Description:Powerex Silic

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak, hermetic Pow-R-Disc devices employing the field proven amplifying gate.

Ordering Information:

Select the complete 12 digit module part number from the table below. Example: T7H8167504DN is a 1600V 750A Phase Control SCR.

Туре	Voltage V _{RRM} (Volts)	Current I _{T(av)} (A)	Turn-off Time t _q (μsec)	Gate Current I _{GT} (mA)	Lead Code
T7H8	02 through 16	75	0	4	DN
	200V through 1600V	750A	150 μsec typical	150 mA	8"

Features:

- ☐ Low On-State Voltage
- ☐ High di/dt Capability
- ☐ High dv/dt Capability
- ☐ Hermetic Packaging
- ☐ Excellent Surge and I²t Ratings

Applications:

- □ Power Supplies
- ☐ Motor Control



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Absolute Maximum Ratings

Characteristics	Symbol		Units
Non-Repetitive Transient Peak Reverse Blocking Voltage	V_{RSM}	V _{RRM} + 100V	Volts
RMS On-State Current, T _C = 62°C	I _{T(RMS)}	1180	Amperes
Average Current 180° Sine Wave, T _C = 62°C	I _{T(AV)}	750	Amperes
RMS On-State Current, T _C = 55°C	I _{T(RMS)}	1260	Amperes
Average Current 180° Sine Wave, T _C = 55°C	I _{T(AV)}	800	Amperes
Peak One Cycle Surge On-State Current (Non-Repetitive) 60 Hz	I _{TSM}	10500	Amperes
Peak One Cycle Surge On-State Current (Non-Repetitive) 50 Hz	I _{TSM}	9600	Amperes
Critical Rate-of-rise of On-State Current (Non-Repetitive)	di/dt	600	A/µsec
Critical Rate-of-rise of On-State Current (Repetitive)	di/dt	150	A/µsec
I ² t (for Fusing) for One Cycle, 60 Hz	l ² t	460,000	A ² sec
Peak Gate Power Dissipation	P_{GM}	16	Watts
Average Gate Power Dissipation	$P_{G(av)}$	3	Watts
Operating Temperature	TJ	-40 to +125	°C
Storage Temperature	T_{stg}	-40 to +150	°C
Approximate Weight		4	OZ.
		113	g
Mounting Force		2000 to 2400	lb.
		900 to 1090	kg.

Information presented is based upon manufacturers testing and projected capabilities. This information is subject to change without notice. The manufacturer makes no claim as to the suitability of use, reliability, capability, or future availability of this product.

Revision Date: 11/13/2007



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Electrical Characteristics, T_J=25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Repetitive Peak Reverse Leakage Current	I _{RRM}	$T_J=125^{\circ}C$, $V_R=V_{RRM}$			30	mA
Repetitive Peak Forward Leakage Current	I_{DRM}	$T_J=125^{\circ}C$, $V_D=V_{DRM}$			30	mA
Peak On-State Voltage	V_{TM}	I _{FM} =625A peak,			1.40	V
		Duty Cycle < 0.1 %				
Threshold Voltage, Low-level	$V_{(TO)1}$	$T_J = 125^{\circ}C$, $I = 15\%I_{T(AV)}$ to $\pi I_{T(AV)}$			0.97192	V
Slope Resistance, Low-level	r _{T1}				0.4818	mΩ
Threshold Voltage, High-level	$V_{(TO)2}$	$T_J = 125^{\circ}C$, $I = \pi I_{T(AV)}$ to I_{TSM}			1.4824	V
Slope Resistance, High-level	r_{T2}	` ,			0.2845	mΩ
V _{TM} Coefficients, Low-level		$T_J = 125^{\circ}C$, $I = 15\%I_{T(AV)}$ to $\pi I_{T(AV)}$		A =	1.221	
				B =	-0.1259	
		$V_{TM} = A + B Ln(I) + C(I) + D Sqrt(I)$		C = D =	8.857 E-04 0.03348	
Typical Turn-On Time	t _{on}	$I_T = 100A, V_D = 100 V$		7	0.000.0	μS
Typical Turn-Off Time	tq	$T_i = 125^{\circ}C, I_T = 250A,$		150		μS
	٩	di _R /dt = 25A/µs Reapplied				
		$dv/dt = 20 V/\mu s$ Linear to 80% V_{DRM}				
Minimum Critical dv/dt – Exponential to V _{DRM}	dv/dt	T _J = 125°C	300			V/µs
Gate Trigger Current	I _{GT}	T _J = 25°C, V _D = 12 V			150	mA
Gate Trigger Voltage	V_{GT}	$T_J = 25^{\circ}C, V_D = 12 V$			3.0	V
Non-Triggering Gate Voltage	V_{GDM}	$T_J = 125$ °C, $V_D = V_{DRM}$			0.15	V
Peak Forward Gate Current	I _{GTM}				4	Α
Peak Reverse Gate Voltage	V_{GRM}				5	V

Thermal Characteristics

Maximum Thermal Resistance, Dou	ble Sided Cooling	Max.	Units
Junction-to-Case	R _{⊙(J-C)}	0.04	°C/W
Case-to-Sink	R _{⊙(C-S)}	0.02	°C/W

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